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**Semiconductor devices - Mechanical and climatic test methods -
Part 34-1: Power cycling test for power semiconductor module**

**Dispositifs à semiconducteurs - Méthodes d'essais mécaniques et climatiques -
Partie 34-1: Essai de cycles en puissance pour modules de puissance à
semiconducteurs**

IEC 60749-34-1:2025

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**Semiconductor devices - Mechanical and climatic test methods -
Part 34-1: Power cycling test for power semiconductor module**

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Draft	Report on voting
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Full information on the voting for its approval can be found in the report on voting indicated in the above table.

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INTRODUCTION

A power semiconductor module is affected by thermal and mechanical stress due to the power dissipation of the internal semiconductor dies and connectors. This occurs when low-voltage operating bias for forward conduction is periodically applied and removed, causing rapid changes in temperature. The power cycling test is intended to simulate the temperature swing in typical power electronics applications, which is different from the stable temperatures reached under the high temperature operating life (HTOL) test as shown in IEC 60749-23. Exposure to the power cycling test would not induce the same failure mechanisms as exposure to the thermal cycling test, or thermal shock test. The power cycling test is a destructive test that will cause wear-out failure of the device under test (DUT) if it is driven above the specification of the device.

The power cycling test is applied to general power semiconductor modules such as for example those used for motor control, robots, and renewable energy generation. The power cycling test has two modes: a short-time test (based on a short cycle time) that simulates rapid acceleration and deceleration of the equipment, and a long-time test (based on a long cycle time) that simulates repeated operation and stop of the equipment. The short-time test mainly verifies the effect of the temperature change of virtual junction temperature (T_{vj}) and causes the deterioration of the joint between the semiconductor die and the wire, and that of the die attach under the semiconductor die. The long-time test verifies the effect of the temperature change of case temperature (T_c) and causes the deterioration of the joining layer between the metallic base plate and the insulating substrate, and the deterioration of the die attach under the semiconductor die.

The power cycling test is performed in two cases: as a certification test for the products whose power cycling lifetime model has already been confirmed, and as a lifetime model validation test for the products whose lifetime model has not been confirmed. The purpose of the certification test is to verify that the product has a longer life than the specified number of cycles.

Moreover, the purpose of the lifetime model validation test is to statistically estimate the power cycling lifetime model from the test results and obtain the expected lifetime model of power modules. This is essential when customers design the lifetime of their products.

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